EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	2	("20010002703").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/02/10 16:17
L3	0	L2 and saturat$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/10 16:17
L4	2	("20050012686").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/02/10 17:20
L5	2	("5814834").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/02/10 17:20
L6	14993	((313/498-500,505) or (315/169.1,169.4) or (345/55,62,76-77,82-84,204)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/02/10 17:20
L7	9425	(suppress$3 eliminat$3 reduc$3 stop$4 quench$3 extinguish$3 squash$3 quell$3 quash$3 remov$3) near10 ((off ((non "not") near3 (on illuminat$3 emiss$3))) near3 current) near10 (transistor$3 tft switch $3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/10 17:20
L8	296	L6 and L7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/10 17:20
L9	2	("20030067424").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/02/10 17:20

L10	2	("20010002703").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/02/10 17:20
L11	2	("20020113760").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/02/10 17:20
L12	2	("6207969").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/02/10 17:20
L13	2	("20050012686").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/02/10 17:20
L14	1	L13 and (threshold near5 (higher and lower)) and (channel near3 length)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/10 17:20
L15	14993	((313/498-500,505) or (315/169.1,169.4) or (345/55,62,76-77,82-84,204)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/02/10 17:20
L16	89	L15 and ((n-channel n-type p-channel p-type) with (threshold near3 (voltage potential)) with (larger greater higher smaller lower))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/10 17:20
L17	19	L15 and ((n-channel n-type p-channel p-type) with (threshold near3 (voltage potential)) with (larger greater higher smaller lower)) and (channel near5 (width and length))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/10 17:20
L18	2	("6870192").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/02/10 17:20
L19	1	L13 and ((channel near3 (width and length)) same (longer smaller equal))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/10 17:20

L20	10	L15 and ((driving near5 (tft transistor)) with saturat$3) and ((current near5 control near5 (transistor tft)) with linear)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/10 17:20
L21	14993	(((313/498-500,505) or (315/169.1,169.4) or (345/55,62,76-77,82-84,204)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/02/10 17:20
L22	10	L21 and ((driving near5 (tft transistor)) with saturat$3) and ((current near5 control near5 (transistor tft)) with (non-saturat$3 linear))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/10 17:20
L23	2	("20050012686").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/02/10 17:20
L24	1	L23 and ((channel near3 (width and length)) same (longer smaller equal))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/10 17:20
L25	1	L23 and (threshold with (higher and lower))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/10 17:20
L26	465	L21 and ((tft transistor) near5 (saturat$3 adj region))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/10 17:22
L27	213	L21 and (pixel same ((tft transistor) near5 (saturat$3 adj region)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/10 17:22
L28	21	L26 and @pd<"20030324"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/10 17:34
S1	2	("20050012686").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/07/07 11:11

S2	2	("5814834").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/08/16 20:15
S3	14061	((313/498-500,505) or (315/169.1,169.4) or (345/55,62,76-77,82-84,204)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/08/16 20:51
S4	9029	(suppress$3 eliminat$3 reduc$3 stop$4 quench$3 extinguish$3 squash$3 quell$3 quash$3 remov$3) near10 ((off ((non "not") near3 (on illuminat$3 emiss$3))) near3 current) near10 (transistor$3 tft switch $3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/08/16 20:55
S5	269	S3 and S4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/08/16 20:56
S6	2	("20030067424").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/08/16 23:59
S7	2	("20010002703").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/08/17 00:34
S8	2	("20020113760").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/08/17 00:50
S9	2	("6207969").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/08/17 00:59
S10	2	("20050012686").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/08/17 01:17

S11	1	S10 and (threshold near5 (higher and lower)) and (channel near3 length)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/08/17 01:17
S12	14061	((313/498-500,505) or (315/169.1,169.4) or (345/55,62,76-77,82-84,204)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/08/17 01:20
S13	85	S12 and ((n-channel n-type p-channel p-type) with (threshold near3 (voltage potential)) with (larger greater higher smaller lower))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/08/17 01:20
S14	16	S12 and ((n-channel n-type p-channel p-type) with (threshold near3 (voltage potential)) with (larger greater higher smaller lower)) and (channel near5 (width and length))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/08/17 01:21
S15	2	("6870192").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/08/17 01:25
S16	1	S10 and ((channel near3 (width and length)) same (longer smaller equal))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/08/17 01:32
S17	9	S12 and ((driving near5 (tft transistor)) with saturat$3) and ((current near5 control near5 (transistor tft)) with linear)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/08/17 01:36
S18	14061	((313/498-500,505) or (315/169.1,169.4) or (345/55,62,76-77,82-84,204)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/08/17 01:41
S19	9	S18 and ((driving near5 (tft transistor)) with saturat$3) and ((current near5 control near5 (transistor tft)) with (non-saturat$3 linear))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/08/17 01:41
S20	2	("20050012686").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/08/17 01:44

| S21 | 1 | S20 and ((channel near3 (width and length)) same (longer smaller equal)) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2008/08/17 01:44 |
| S22 | 1 | S20 and (threshold with (higher and lower)) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2008/08/17 01:54 |

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